



Product Overview

MC74HC4046A: Phase Locked Loop

For complete documentation, see the data sheet

Product Description

High-Performance Silicon-Gate CMOS

The MC74HC4046A is similar in function to the MC14046 Metal gate CMOS device. The device inputs are compatible with standard CMOS outputs; with pullup resistors, they are compatible with LSTTL outputs.

The HC4046A phase-locked loop contains three phase comparators, a voltage-controlled oscillator (VCO) and unity gain op-amp DEM_{OUT}. The comparators have two common signal inputs, COMP_{IN}, and SIG_{IN}. Input SIG_{IN} and COMP_{IN} can be used directly coupled to large voltage signals, or indirectly coupled (with a series capacitor to small voltage signals). The self-bias circuit adjusts small voltage signals in the linear region of the amplifier. Phase comparator 1 (an exclusive OR gate) provides a digital error signal PC1_{OUT} and maintains 90 degrees phase shift at the center frequency between SIG_{IN} and COMP_{IN} signals (both at 50% duty cycle). Phase comparator 2 (with leading-edge sensing logic) provides digital error signals PC2_{OUT} and PCP_{OUT} and maintains a 0 degree phase shift between SIG_{IN} and COMP_{IN} signals (duty cycle is immaterial). The linear VCO produces an output signal VCO_{OUT} whose frequency is determined by the voltage of input VCO_{IN} signal and the capacitor and resistors connected to pins C1A, C1B, R1 and R2. The unity gain op-amp output DEM_{OUT} with an external resistor is used where the VCO_{IN} signal is needed but no loading can be tolerated. The inhibit input, when high, disables the VCO and all op-amps to minimize standby power consumption.

Applications include FM and FSK modulation and demodulation, frequency synthesis and multiplication, frequency discrimination, tone decoding, data synchronization and conditioning, voltage-to-frequency conversion and motor speed control.

Features

- Output Drive Capability: 10 LSTTL Loads
- Low Power Consumption Characteristic of CMOS Devices
- Operating Speeds Similar to LSTTL
- Wide Operating Voltage Range: 3.0 to 6.0 V
- Low Input Current: 1.0 μ A Maximum (except SIG_{IN} and COMP_{IN})
- In Compliance with the Requirements Defined by JEDEC Standard No. 7A
- Low Quiescent Current: 80 μ A Maximum (VCO disabled)
- High Noise Immunity Characteristic of CMOS Devices
- Diode Protection on all Inputs
- Chip Complexity: 279 FETs or 70 Equivalent Gates

Part Electrical Specifications

Product	Compliance	Status	Input Level	Output Level	f _{Max} Typ (MHz)	V _{CC} Typ (V)	Duty Cycle (%)	Package Type
MC74HC4046ADG	Pb-free Halide free	Active	CMOS	CMOS	3	6	50	SOIC-16
MC74HC4046ADR2G	Pb-free Halide free	Active	CMOS	CMOS	3	6	50	SOIC-16
MC74HC4046ADTG	Pb-free Halide free	Active	CMOS	CMOS	3	6	50	TSSOP-16
MC74HC4046ADTR2G	Pb-free Halide free	Active	CMOS	CMOS	3	6	50	TSSOP-16
NLV74HC4046ADR2G	AEC Qualified PPAP Capable Pb-free Halide free	Active	CMOS	CMOS	3	6	50	SOIC-16

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